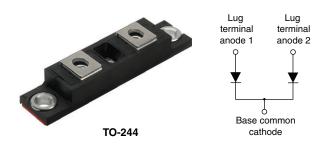
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High Performance Schottky Rectifier, 400 A



PRIMARY CHARACTERISTICS			
I _{F(AV)}	400 A		
V _R	100 V		
Package	TO-244		
Circuit configuration	Two diodes common cathode		

FEATURES

- 175 °C T_J operation
- Center tap module
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- UL approved file E222165
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

The VS-403CNQ... center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	400	А		
V _{RRM}		100	V		
I _{FSM}	t _p = 5 μs sine	25 500	А		
V _F	200 A _{pk} , T _J = 125 °C (per leg)	0.69	V		
TJ	Range	-55 to +175	۵°		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-403CNQ100PbF	UNITS	
Maximum DC reverse voltage	V _R	100	V	
Maximum working peak reverse voltage	V _{RWM}	100	v	

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward	per leg		$I_{F(AV)}$ 50 % duty cycle at T _C = 141 °C, rectangular waveform		200	
current See fig. 5	per device				$_{(AV)}$ 50 % duty cycle at $T_C = 141$ °C, rectangular was	, rectangular wavelonn
Maximum peak one cycle non-repetitive surge current per leg I _{FSM} See fig. 7			5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	25 500	A
		IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	3300	
Non-repetitive avalanche energy per leg E _{AS}		T _J = 25 °C, I _{AS} = 13 A, L = 0.2 mH		15	mJ	
Repetitive avalanche current p	er leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1	А

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ELECTRICAL SPECIFICATIONS

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONE	VALUES	UNITS	
Maximum forward voltage drop per leg See fig. 1	V _{FM} ⁽¹⁾	200 A	T.I = 25 °C	0.84	V
		400 A	1j=25 C	1.07	
		200 A	T T D D	0.69	
		400 A	$T_J = T_J maximum$	0.82	
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	6	mA
See fig. 2		T _J = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	80	
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		5500	pF
Typical series inductance per leg	Ls	From top of terminal hole to mounting plane		5.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}	-55	-	175	°C	
Thermal resistance, junction to case per leg	Р	-	-	0.19		
Thermal resistance, junction to case per module	– R _{thJC}	-	-	0.095	°C/W	
Thermal resistance, case to heatsink	R _{thCS}	-	0.10	-		
Weight		-	68	-	g	
		-	2.4	-	oz.	
Mounting torque		35.4 (4)		53.1 (6)		
Mounting torque center hole		30 (3.4)		40 (4.6)	lbf ⋅ in (N ⋅ m)	
Terminal torque		30 (3.4)	-	44.2 (5)		
Vertical pull		-	-	80	lhf in	
2" lever pull		-	-	35	- lbf · in	

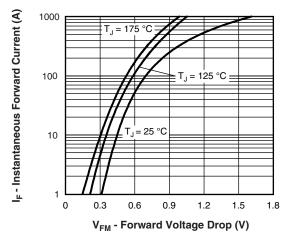
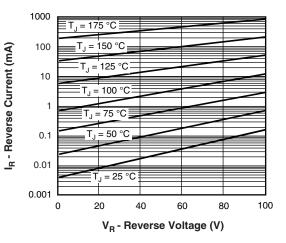
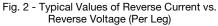


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)





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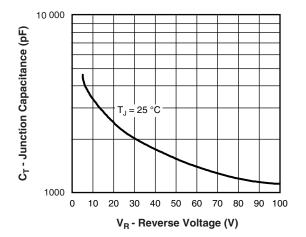


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

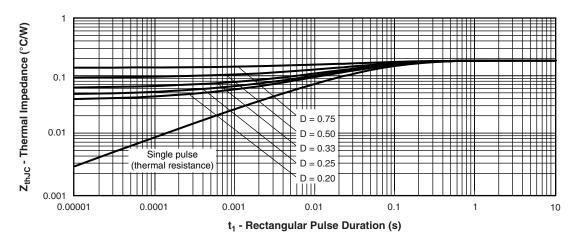


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

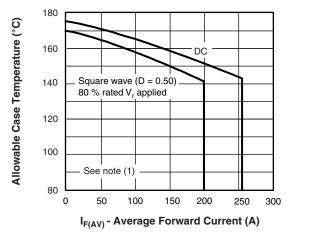


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

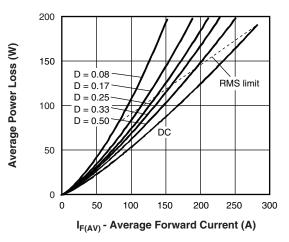


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

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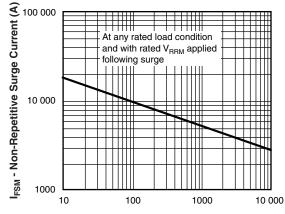
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t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

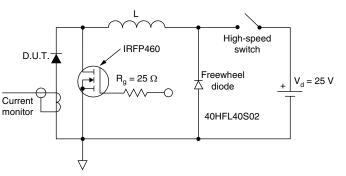


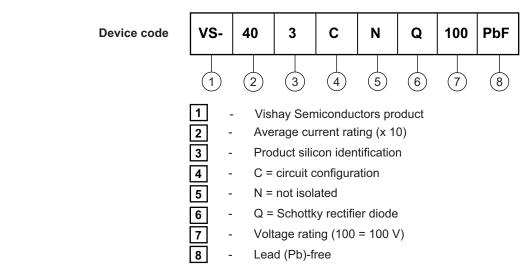
Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \, \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \, \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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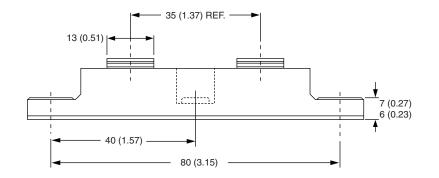


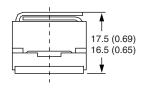


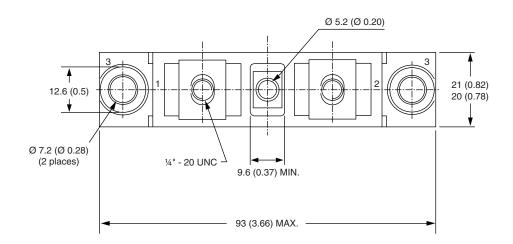
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TO-244

DIMENSIONS in millimeters (inches)









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